

Zener diode

FTZ5.6E

● Applications

Constant voltage control
Noise suppression on signal line

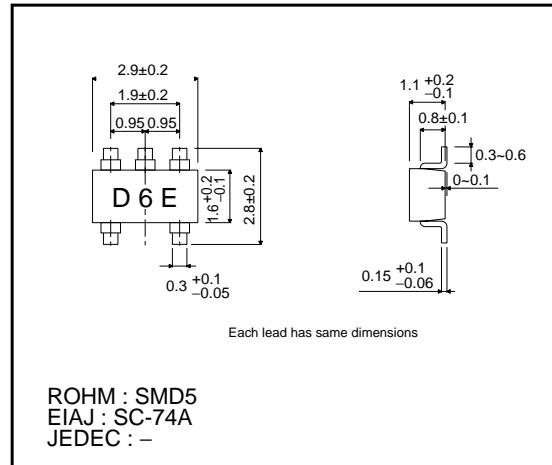
● Features

- 1) Small surface mounting type.(SMD5)
- 2) Multiple diodes with common anode configuration.
- 3) High reliability.

● Construction

Silicon epitaxial planar

● External dimensions (Units : mm)

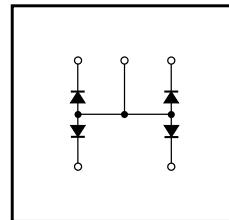


● Absolute maximum ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Power dissipation*	P	200	mW
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55~+125	$^\circ\text{C}$

* Total of 4 elements

● Equivalent circuit



● Electrical characteristics ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Zener voltage	V_z	5.31	–	5.92	V	$I_z=5\text{mA}$
Reverse current	I_R	–	–	1	μA	$V_R=2.5\text{V}$
Operating resistance	Z_z	–	–	60	Ω	$I_z=5\text{mA}$
Rising operating resistance	Z_{zK}	–	–	200	Ω	$I_z=0.5\text{mA}$

● Others

Parameter	IEC61000-4-2
Device configuration	<ul style="list-style-type: none"> · Charge / discharge capacitance : 150pF · Discharge resistance : 330Ω
Judgment contents	<ul style="list-style-type: none"> · 10 repetitions · No malfunction · Contact : $\pm 8\text{kV}$ · Suspended : $\pm 15\text{kV}$

Diodes

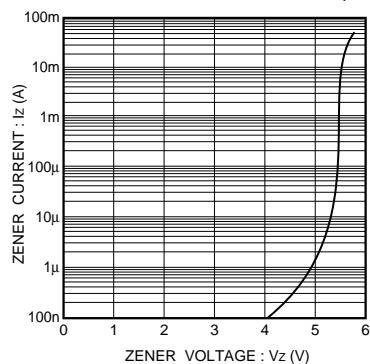
●Electrical characteristic curve (Ta=25°C)

Fig.1 Zener characteristics

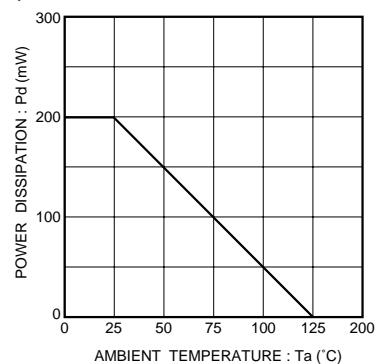


Fig.2 Derating curve